Docket No.: 1016-012 <

the specification of which is attached hereto

## **DECLARATION AND POWER OF ATTORNEY**

As a below named inventor, I hereby declare that:

My residence, post office address, and citizenship are as stated below next to my name,

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter claimed and for which a patent is sought on the invention entitled:

## VIA-SEA LAYOUT IN INTEGRATED CIRCUITS

	_ as Application	Serial No and was amende	ed on (i	f applicable).
=		ed and understand the conte as amended by any amendmer		
America before the the same was not it prior to this application	is invention there in public use or of cation. I acknowl	the same was ever known or of or more than one year prior n sale in the United States of edge the duty to disclose info n accordance with title 37, C	r to this app America mo ormation wh	lication, and that ore than one year nich is known to
or Section 365(b) 365(a) of any PCT the United States, patent or inventor	of any foreign ap international applisted below and 's certificate have	fits under Title 35, United Sta oplication(s) for patent or inve- plication which designated at d have also identified below ing a filing date before that	entor's certification least one contains any foreign	ficate, or Section buntry other than application for
priority is claimed:	•			
Prior Foreign Ap			Priority (	Claimed
		Day/Month/Year filed	Priority ( <u>Yes</u>	Claimed <u>No</u>
Prior Foreign Ap	plication(s): <u>Country</u> benefit under 35	<u>Day/Month/Year filed</u> USC 119(e) of any United Sta	Yes	<u>No</u>
Prior Foreign Ap  Number  I hereby claim the	Country benefit under 35 d below:		Yes	<u>No</u>
Number  I hereby claim the application(s) liste	Country benefit under 35 d below: Application(s):		Yes	<u>No</u>

I hereby claim the benefit under Title 35, United States Code, Section 120 of any United States application(s), or Section 365(c) of any PCT international application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT international application in the manner provided by the first paragraph of Title 35, United States Code, Section 112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, Section 1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

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## **Prior U.S. Application(s):**

Serial No.

Filing Date

Status: Patented, Pending, Abandoned

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

I hereby revoke any previous Powers of Attorney and appoint the following attorney(s) and/or agent(s), each said individual being a member or associate of The Law Offices of Mikio Ishimaru or being employed by Chartered Semiconductor Manufacturing Ltd.:

Mikio Ishimaru

Reg. No. 27,449

for so long as they remain with such law offices or company with full power of substitution and revocation, to prosecute this application and to transact in connection therewith all business in the Patent and Trademark Office and before competent International Authorities; said appointment to be to the exclusion of myself and my other attorney(s); and all future correspondence should be addressed to:

Mikio Ishimaru
The Law Offices of Mikio Ishimaru
1110 Sunnyvale – Saratoga Rd., Suite A1
Sunnyvale, California 94087

Inventor's signature:	Wh	Date:	5/NOV ,	1200/

Full name of sole or first inventor: Jae Soo Park

i an name of sole of mot i

Citizenship:

Residence Address, including

country:

3ac 500 1 ai

Korea Norea

56A Toh-Tuck Road, #07-04

Signature Park

Singapore 596746

P.O. Address:

c/o Chartered Semiconductor Manufacturing Ltd.

60 Woodlands Industrial Park D.

Street 2

Singapore 738406

Docket No.: 1016-012

Date:

Chivukula Subramanyam

Citizenship:

India

Residence Address, including

Blk 557, Aug Mo Kio Ave 10

country:

#07-1866

Singapore 560557

Post Office Address:

c/o Chartered Semiconductor Manufacturing Ltd.

60 Woodlands Industrial Park D.

Street 2

Singapore 738406

Inventor's signature:

hunt 10

Date: 20/12/2001

Full name of joint inventor:

Thow Phock Chua

Citizenship:

Singapore

Residence Address, including

Blk 42 Cassia Crescent

country:

#05-210

Singapore, 390042

Post Office Address:

c/o Chartered Semiconductor Manufacturing Ltd.

60 Woodlands Industrial Park D.

Street 2

Singapore 738406

Inventor's signature:

Full name of joint inventor:

Citizenship:

Hong Lim Lee Malaysia

Residence Address, including

country:

2A Jalan Bakti Serene Park

81300 Johor Bahru,

Malaysia

P.O. Address:

c/o Chartered Semiconductor Manufacturing Ltd.

60 Woodlands Industrial Park D.

Street 2

Singapore 738406